



RS1G175 Single D-Type Flip-Flop with Asynchronous Clear

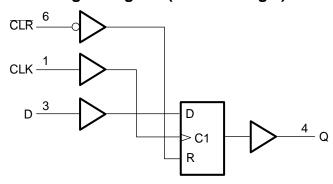
1 FEATURES

- Operating Voltage Range:1.65V to 5.5V
- Low Power Consumption:10μA (Max)
- Operating Temperature Range: -40°C to +125°C
- Inputs Accept Voltage to 5.5V
- High Output Drive: ±24mA at V_{CC}=3.0V
- I_{off} Supports Live Insertion, Partial-Power-Down Mode, and Back-Drive Protection
- Micro SIZE PACKAGES: SOT23-6, SOT363(SC70-6)

2 APPLICATIONS

- Enterprise Switching
- Telecom Infrastructure
- Servers
- Medical Healthcare and Fitness
- PC/Notebook
- Motor Drives

Logic Diagram (Positive Logic)



3 DESCRIPTIONS

The RS1G175 single D-type flip-flop is designed for 1.65V to 5.5V Vcc operation.

The RS1G175 device has an asynchronous clear (\overline{CLR}) input. When \overline{CLR} is high, data from the input pin (D) is transferred to the output pin (Q) on the clock's (CLK) rising edge. When \overline{CLR} is low, Q is forced into the low state, regardless of the clock edge or data on D.

The RS1G175 is fully specified for partial-power-down applications using l_{off}. The l_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

This device available in Green SOT23-6 and SOT363(SC70-6) packages. It operates over an ambient temperature range of -40°C to +125°C.

Device Information (1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)
RS1G175	SOT363 (SC70-6)	2.10mm×1.25mm
	SOT23-6(6)	1.60mm×2.92mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



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4 Revision History
Note: Page numbers for previous revisions may different from page numbers in the current version.

Version	Change Date	Change Item
A.0	2023/05/09	Preliminary version completed
A.1	2023/06/28	Update Timing Requirements and Switching Characteristics



5 PACKAGE/ORDERING INFORMATION (1)

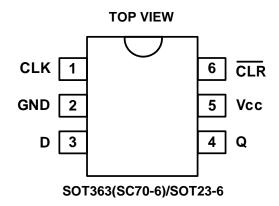
PRODUCT	ORDERING NUMBER			PACKAGE MARKING (2)	PACKAGE OPTION
DC4.C475	RS1G175XC6	-40°C ~+125°C	SOT363(SC70-6)	1G175	Tape and Reel,3000
RS1G175	RS1G175XH6	-40°C ~+125°C	SOT23-6	1G175	Tape and Reel,3000

NOTE:

- (1) This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the right-hand navigation.
- (2) There may be additional marking, which relates to the lot trace code information (data code and vendor code), the logo or the environmental category on the device.



6 PIN CONFIGURATIONS



6.1 PIN DESCRIPTION

PIN	NAME	I/O TYPE (1)	FUNCTION
SOT363(SC70-6)/SOT23-6	NAIVIE	//OTTPE	FUNCTION
1	CLK	I	Clock Input
2	GND	Р	Ground
3	D	I	Input
4	Q	0	Output
5	Vcc	Р	Power pin
6	CLR	I	Clear Data Input

⁽¹⁾ I=input, O=output, P=power.

6.2 FUNCTION TABLE

	OUTPUT		
CLR	CLK	D	Q
Н	1	L	L
Н	↑	Н	Н
Н	H or L	X	Q_0
L	Х	Х	L

⁽¹⁾ H=High Voltage Level L=Low Voltage Level X=Don't Care



7 SPECIFICATIONS

7.1 Absolute Maximum Ratings (1)

over operating free-air temperature range (unless otherwise noted) (1) (2)

			MIN	MAX	UNIT
Vcc	Supply voltage range	-0.5	6.5	V	
Vı	Input voltage range (2)		-0.5	6.5	V
Vo	Voltage range applied to any output in the high	n-impedance or power-off state (2)	-0.5	6.5	V
Vo	Vo Voltage range applied to any output in the high or low state (2) (3)				V
lıĸ	Input clamp current	V _I <0		-50	mA
Іок	Output clamp current	Vo<0		-50	mA
lo	Continuous output current	·		±50	mA
	Continuous current through V _{CC} or GND			±100	mA
θда	Package thermal impedance (4)	SOT363(SC70-6)		265	°C/W
ÐJA	Package thermal impedance (*)		230	C/VV	
ТJ	T _J Junction temperature ⁽⁵⁾				°C
Tstg	Storage temperature	-65	150	°C	

⁽¹⁾ Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V_{CC} is provided in the Recommended Operating Conditions table.
- (4) The package thermal impedance is calculated in accordance with JESD-51.
- (5) The maximum power dissipation is a function of $T_{J(MAX)}$, $R_{\theta JA}$, and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} T_A) / R_{\theta JA}$. All numbers apply for packages soldered directly onto a PCB.

7.2 ESD Ratings

The following ESD information is provided for handling of ESD-sensitive devices in an ESD protected area only.

		VALUE	UNIT
	Human-body model (HBM)	±2000	
$V_{\left(ESD \right)}$ Electrostatic discharge	Charged-device model (CDM)	±1000	V
	Machine model (MM)	±200	



ESD SENSITIVITY CAUTION

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

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8 ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (TYP values are at T_A = +25°C, Full=-40°C to 125°C, unless otherwise noted.) (1)

8.1 Recommended Operating Conditions

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
Supply voltage	Vcc	Operating	1.65	5.5	V
		V _{CC} =1.65V to 1.95V	0.75 x Vcc		
High lavel is suit valtage	.,,	V _{CC} =2.3V to 2.7V	1.7		V
High-level input voltage	VIH	V _{CC} =3V to 3.6V	2		V
		V _{CC} =4.5V to 5.5V	0.7 x Vcc		
		V _{CC} =1.65V to 1.95V		0.25 x V _{CC}	
Law lavel input veltage	V.	V _{CC} =2.3V to 2.7V		0.7	V
Low-level input voltage	VIL	V _{CC} =3V to 3.6V		0.8	V
		V _{CC} =4.5V to 5.5V		0.3 x Vcc	
Input voltage	Vı		0	5.5	V
Output voltage	Vo		0	Vcc	V
	rent Іон	V _{CC} =1.65V		-4	
		V _{CC} =2.3V		-8	
High-level output current		\/=2\/		-16	mA
		Vcc=3V		-24	
		V _{CC} =4.5V		-32	
		V _{CC} =1.65V		4	
		V _{CC} =2.3V		8	
Low-level output current	loL	\/=2\/		16	mA
		V _{CC} =3V		24	
		V _{CC} =4.5V		32	
		V _{CC} =1.8V± 0.15V,2.5V ± 0.2V		20	
Input transition rise or fall	Δt / Δν	V _{CC} =3.3V± 0.3V		10	ns/V
		V _{CC} =5V± 0.5V		10	
Operating temperature	T _A		-40	+125	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.



8.2 DC Characteristics

F	PARAMETER	TEST CONDITIONS	Vcc	TEMP	MIN ⁽²⁾	TYP ⁽³⁾	MAX ⁽²⁾	UNIT
		Іон = -100μΑ	1.65V to 5.5V		Vcc-0.1			
		I _{OH} = -4mA	1.65V		1.2			
	Vон	I _{OH} = -8mA	2.3V	Full	1.9			V
	VOH	I _{OH} = -16mA	3V	Full	2.4			V
	I _{OH} = -24mA	3 V		2.3				
		I _{OH} = -32mA	4.5V		3.8			
		I _{OL} = 100μA	1.65V to 5.5V				0.1	
		I _{OL} = 4mA	1.65V				0.45	
	\/	I _{OL} = 8mA	2.3V	Full			0.3	V
	Vol	I _{OL} = 16mA	3V	ruii			0.4	
		I _{OL} = 24mA	3 v				0.55	
		I _{OL} = 32mA	4.5V				0.55	
lı	Data or control	V _I =5.5V or GND	0V to 5.5V	+25°C		±0.1	±1	
II	inputs	VI=5.5V OI GIND	00 10 5.50	Full			±5	μA
	l _{off}	Vior Vo=5.5V	0	+25°C		±0.1	±1	
	TOTT	V101 V0=3.5V	U	Full			±10	μA
	laa	V _I =5.5V or GND, I _O =0	1.65V to 5.5V	+25°C		0.1	1	۸
Icc	V =5.5V OI GND, 10=0	1.03 0 10 3.3 0	Full			10	μA	
	ΔΙσο	One input at Vcc-0.6V, Other inputs at Vcc or GND	3V to 5.5V	Full			500	μΑ
C _i (In	put Capacitance)	$V_I = V_{CC}$ or GND	3.3V	+25°C		5.5		pF

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

8.3 Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted) (1)

PARAM FROM		то	TEMP		=1.8V .15V		=2.5V).2V		=3.3V).3V		=5V .5V	UNIT
ETER (INI	(INPUT)	(OUTPUT)		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{clock}			-40°C to 85°C		30		65		100		155	MHz
Iclock			-40°C to 125°C						100		155	IVITZ
	CIKH	igh or low	-40°C to 85°C	8		4		3		2		
	CLK High or low	ign or low	-40°C to 125°C					3		2		
tw	t _w	R low	-40°C to 85°C	12		5		3.4		2		
	CL	K IOW	-40°C to 125°C					3.4		2		
	_	Data	-40°C to 85°C	10.4		4.6		3.2		2		no
4	_	Jala	-40°C to 125°C					3.2		2		ns
t _{su}	CLD	inactiva	-40°C to 85°C	8.4		3.8		2.6		1.8		
LI CI	CLK	CLR inactive	-40°C to 125°C					2.6		1.8		
4.			-40°C to 85°C	0.5		0.5		0.5		0.5		
t _h		-40°C to 125°C					0.5		0.5			

⁽¹⁾ This parameter is ensured by design and/or characterization and is not tested in production.

⁽²⁾ Limits are 100% production tested at 25°C. Limits over the operating temperature range are ensured through correlations using statistical quality control (SQC) method.

⁽³⁾ Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration.



8.4 Switching Characteristics

over recommended operating free-air temperature range, C_L = 15 pF (unless otherwise noted) (1)

PARAM	FROM	то	TEMP	V _{CC} =1.8V ± 0.15V						V _{cc} =5V ± 0.5V		UNIT
ETER	(INPUT)	(OUTPUT)	· - · · · ·	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{max}			-40°C to 85°C	30		65		100		155		MHz
4 .	CLK	Q	-40°C to 85°C	2.5	25.5	2	13	1.4	9.5	1	7	no
t _{pd}	CLR	Q	-40°C to 85°C	2.5	23	2	10	1.2	7.5	1	6	ns

⁽¹⁾ This parameter is ensured by design and/or characterization and is not tested in production.

8.5 Switching Characteristics

over recommended operating free-air temperature range, C_L = 30 pF or 50 pF (unless otherwise noted) (1)

PARAM ETER	FROM	_	_	_	_	_	_	_	то	TEMP		:1.8V :15V		=2.5V).2V		=3.3V .3V		=5V .5V	UNIT
	(INPUT)	(OUTPUT)		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	0							
f			-40°C to 85°C	30		65		100		155		MHz							
f _{max}			-40°C to 125°C					100		155		IVIITZ							
	CLK	Q	-40°C to 85°C	2.7	27.5	2.2	14.1	1.6	11	1.5	8.2								
	CLK	Q	-40°C to 125°C	2.7	28.3	2.2	15	1.6	11.5	1.5	9	20							
t _{pd}	CLD	<u>CLD</u>	0	-40°C to 85°C	2.7	24.5	2.2	11	1.5	9	1.3	7	ns						
	CLR	Q	-40°C to 125°C	2.7	25	2.2	12	1.5	9.5	1.3	7.5								

⁽¹⁾ This parameter is ensured by design and/or characterization and is not tested in production.

8.6 Operating Characteristics

 $T_A = +25^{\circ}C$

PARAMETER		TEST	Vcc = 1.8V	Vcc = 2.5V	Vcc = 3.3V	Vcc = 5V	UNIT	
	PARAMETER	CONDITIONS	TYP	TYP	TYP	TYP	CINIT	
	C _{pd} Power dissipation capacitance	f = 10 MHz	12	16	21	24	pF	

8.7 TYPICAL CHARACTERISTICS

NOTE: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only.

At T_A = +25°C, unless otherwise noted.

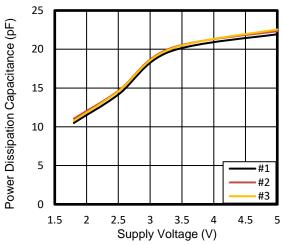
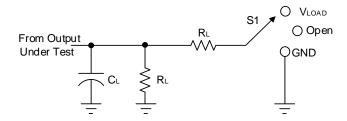


Figure 1. Voltage vs Capacitance

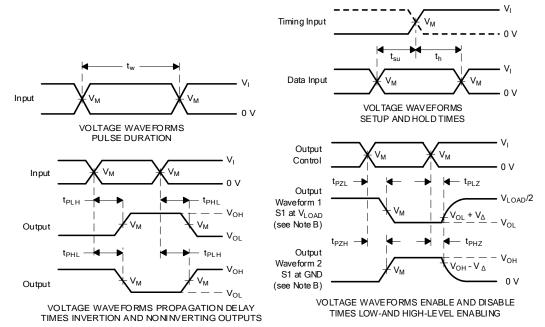


9 Parameter Measurement Information



TEST	S1			
tplh/tphl	Open			
t _{PLZ} /t _{PZL}	V _{LOAD}			
t _{PHZ} /t _{PZH}	GND			

V	INP	UTS	V	V).	VΔ
Vcc	Vı	t _r /t _f	V _M	V _{LOAD}	C∟		R∟		ν Δ
1.8V±0.15V	Vcc	≤2ns	V _{CC} /2	2 x V _{CC}	15pF	30pF	1ΜΩ	1kΩ	0.15V
2.5V±0.2V	Vcc	≤2ns	Vcc/2	2 x Vcc	15pF	30pF	1ΜΩ	500Ω	0.15V
3.3V±0.3V	3V	≤2.5ns	1.5V	6V	15pF	50pF	1ΜΩ	500Ω	0.3V
5V±0.5V	Vcc	≤2.5ns	Vcc/2	2 x Vcc	15pF	50pF	1ΜΩ	500Ω	0.3V



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Zo = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

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10 Detailed Description

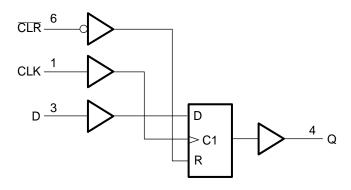
10.1 Overview

This single D-type flip-flop is designed for 1.65V to 5.5V V_{CC} operation.

The RS1G175 device has an asynchronous clear (\overline{CLR}) input. When \overline{CLR} is high, data from the input pin (D) is transferred to the output pin (Q) on the clock's (CLK) rising edge. When \overline{CLR} is low, Q is forced into the low state, regardless of the clock edge or data on D.

This device is fully specified for partial-power-down applications using loff. The loff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

10.2 Functional Block Diagram



10.3 Feature Description

The RS1G175 device has a wide operating V_{CC} range of 1.65 V to 5.5 V, which allows it to be used in a broad range of systems. The 5.5V I/Os allow down translation and also allow voltages at the inputs when $V_{CC} = 0$.



11 Application and Implementation

Information in the following applications sections is not part of the RUNIC component specification, and RUNIC does not warrant its accuracy or completeness. RUNIC's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

11.1 Application Information

Multiple RS1G175 devices can be used in tandem to create a shift register of arbitrary length. In this example, we use four RS1G175 devices to form a 4-bit serial shift register. By connecting all CLK inputs to a common clock pulse and tying each output of one device to the next, we can store and load 4-bit values on demand. We demonstrate loading the 4-bit value 1101 into memory by setting Serial Input Data to each desired memory bit, and by sending a clock pulse for each bit, we sequentially move all stored bits from left to right (A \rightarrow B \rightarrow C \rightarrow D)

11.2 Typical Application

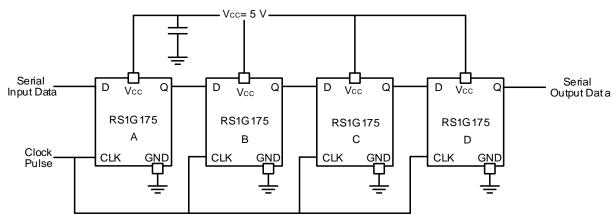


Figure 3. 4-Bit Serial Shift Register

Table 1. Stored Data Values										
Serial Input Data	Stored A	Stored B	Stored C	Stored D						
1	0	0	0	0						
0	1	0	0	0						
1	0	1	0	0						
1	1	0	1	0						
0	1	1	0	1						

Table 1. Stored Data Values

11.3 Design Requirements

The RS1G175 device uses CMOS technology and has balanced output drive. Care must be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The RS1G175 allows storing digital signals with a digital control signal. All input signals should remain as close as possible to either 0 V or Vcc for optimal operation.

12 Power Supply Recommendations

The power supply pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1uF capacitor is recommended and if there are multiple V_{CC} terminals then 0.01uF or 0.022uF capacitors are recommended for each power terminal. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1µF and 1µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible.



13 Layout

13.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 4 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC}, whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.

13.2 Layout Example

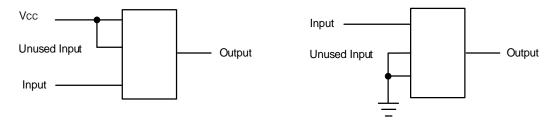
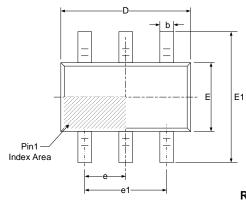
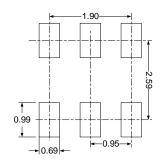


Figure 4. Layout Diagram

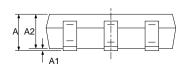


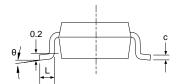
14 PACKAGE OUTLINE DIMENSIONS SOT23-6





RECOMMENDED LAND PATTERN (Unit: mm)

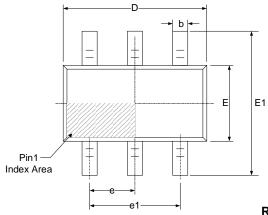


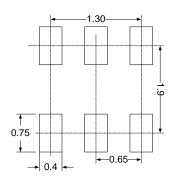


Cumbal	Dimensions I	In Millimeters	Dimensions In Inches			
Symbol	Min	Max	Min	Max		
А	1.050	1.250	0.041	0.049		
A1	0.000	0.100	0.000	0.004		
A2	1.050	1.150	0.041	0.045		
b	0.300	0.500 0.012		0.020		
С	0.100	0.200	0.004	0.008		
D	2.820	3.020	0.111	0.119		
E	1.500	1.700	0.059	0.067		
E1	2.650	2.950	0.104	0.116		
е	e 0.950(B		0.037	(BSC)		
e1	1.800	2.000	0.071	0.079		
L	0.300	0.600	0.012	0.024		
θ	0°	8°	0°	8°		

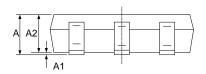


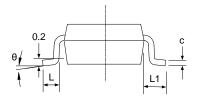
SOT363(SC70-6)





RECOMMENDED LAND PATTERN (Unit: mm)





Complete	Dimensions I	n Millimeters	Dimension	s In Inches	
Symbol	Min	Max	Min	Max	
А	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.150	0.350	0.006	0.014	
С	0.080	0.150	0.003	0.006	
D	2.000	2.200	0.079	0.087	
Е	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.650	(BSC)	0.026	(BSC)	
e1	1.300	(BSC)	0.051	(BSC)	
L	0.260	0.460	0.010	0.018	
L1	0.5	525	0.021		
θ	0°	8°	0°	8°	

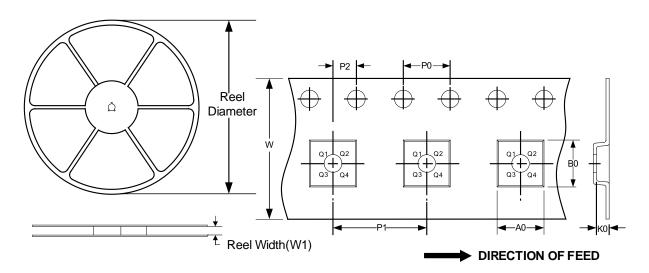
NOTE:

- A. All linear dimension is in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 D. BSC: Basic Dimension. Theoretically exact value shown without tolerances.



15 TAPE AND REEL INFORMATION REEL DIMENSIONS

TAPE DIMENSION



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width(mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOT363(SC70-6)	7"	9.5	2.40	2.50	1.20	4.0	4.0	2.0	8.0	Q3
SOT23-6	7"	9.5	3.17	3.23	1.37	4.0	4.0	2.0	8.0	Q3

NOTE:

- 1. All dimensions are nominal.
- 2. Plastic or metal protrusions of 0.15mm maximum per side are not included.



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